



MBR30100CT thru MBR30200CT

30.0A Schottky Barrier Rectifiers

Rectifier Reverse Voltage 100 to 200V

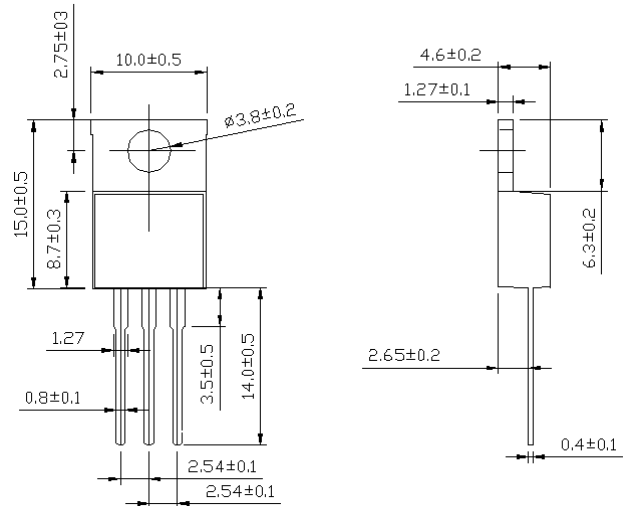
TO-220

Features

- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- Solder dip 260 °C max. 8 s, per JESD 22-B106

Mechanical Data

- **Package:** TO-220AB
Molding compound meets UL 94 V-0 flammability rating, RoHS-compliant
- **Terminals:** Tin plated leads, solderable per J-STD-002 and JESD22-B102
- **Polarity:** As marked



Dimensions in millimeters (1mm =0.0394")

■Maximum Ratings (T_a=25°C Unless otherwise specified)

| PARAMETER | SYMBOL | UNIT | MBR30100CT | MBR30150CT | MBR30200CT |
|--|------------------|------------------|------------|------------|------------|
| Device marking code | | | MBR30100CT | MBR30150CT | MBR30200CT |
| Repetitive Peak Reverse Voltage | VRRM | V | 100 | 150 | 200 |
| Average Rectified Output Current @60Hz sine wave, R-load, T _a =25°C | I _O | A | 30 | | |
| Surge(Non-repetitive)Forward Current @60Hz half sine-wave, 1 cycle, T _a =25°C | I _{FSM} | A | 180 | | |
| Current Squared Time @1ms≤t<8.3ms T _j =25°C, | I ² t | A ² s | 134 | | |
| Storage Temperature | T _{stg} | °C | -55 ~ +175 | | |
| Junction Temperature | T _j | °C | -55 ~ +150 | | |

■Electrical Characteristics (T_a=25°C Unless otherwise specified)

| PARAMETER | SYMBOL | UNIT | TEST CONDITIONS | MBR30100CT | MBR30150CT | MBR30200CT |
|---|-------------------|------|--|------------|------------|------------|
| Maximum instantaneous forward voltage drop per diode | V _{FM} | V | I _{FM} =15.0A | 0.87 | 0.93 | 0.95 |
| Maximum DC reverse current at rated DC blocking voltage per diode | I _{RRM1} | mA | V _{RM} =V _{RRM} T _a =25°C | 0.15 | 0.1 | |
| | I _{RRM2} | | V _{RM} =V _{RRM} T _a =125°C | 20 | | |
| Thermal Resistance | R _{θJ-C} | °C/W | Between junction and case | 2.0 | | |

Rating and Characteristic Curves ($T_A=25^\circ\text{C}$ Unless otherwise noted)

MBR30100CT thru MBR30200CT

FIG1: I_o - T_c Curve

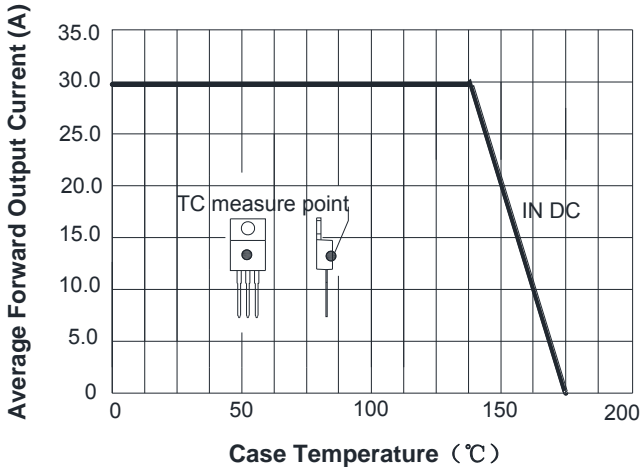


FIG2: Surge Forward Current Capability

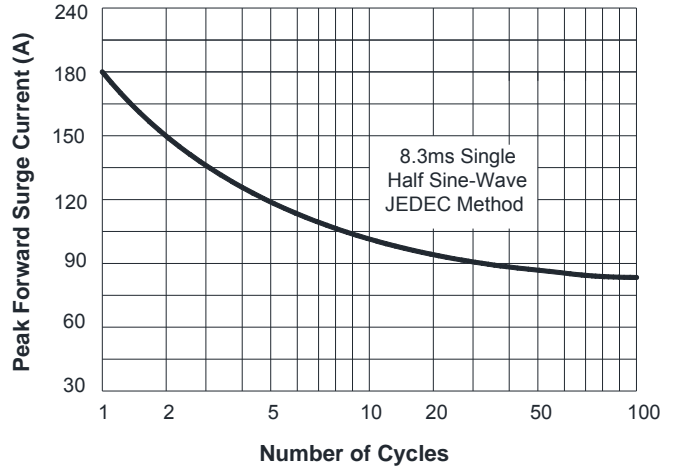


FIG3: Forward Voltage

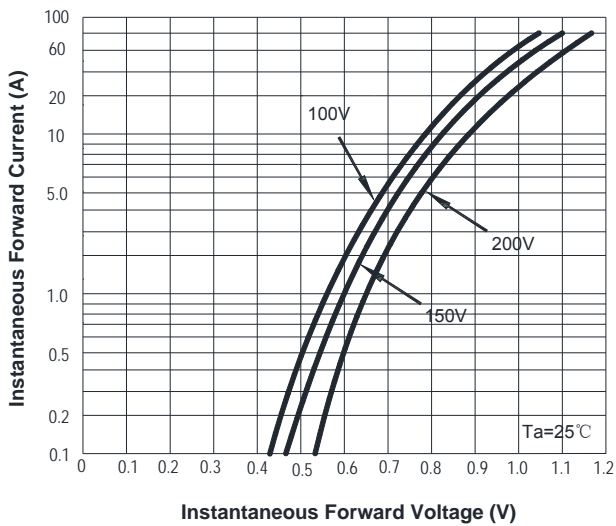
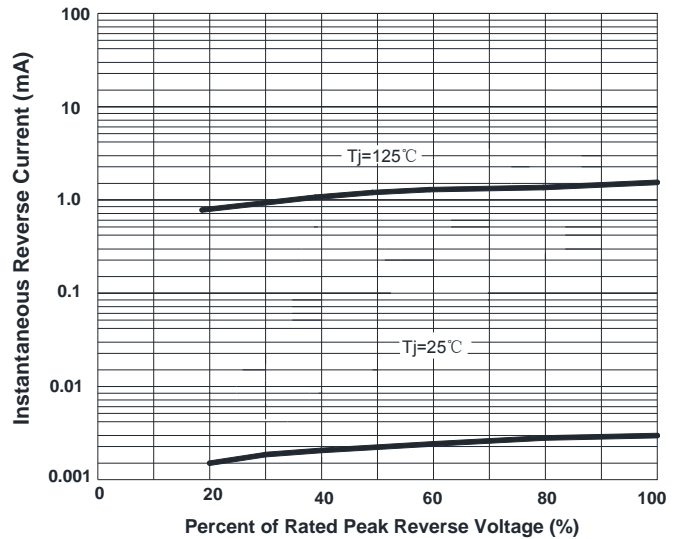


FIG4: Instantaneous Reverse Characteristics



X-ON Electronics

Largest Supplier of Electrical and Electronic Components

Click to view similar products for [Schottky Diodes & Rectifiers](#) category:

Click to view products by [Shandong Baocheng](#) manufacturer:

Other Similar products are found below :

[MA4E2039](#) [MMBD301M3T5G](#) [RB160M-50TR](#) [D83C](#) [BAS16E6433HTMA1](#) [BAS 3010S-02LRH E6327](#) [BAT 54-02LRH E6327](#)
[NRVBAF360T3G](#) [NSR05F40QNXT5G](#) [NTE555](#) [JANS1N6640](#) [SS3003CH-TL-E](#) [GA01SHT18](#) [CRS10I30A\(TE85L,QM](#) [MBRA140TRPBF](#)
[MBRB30H30CT-1G](#) [BAT 15-04R E6152](#) [JANTX1N5712-1](#) [DMJ3940-000](#) [SB007-03C-TB-E](#) [NRVBB20100CTT4G](#) [NRVBM120LT1G](#)
[NTSB30U100CT-1G](#) [CRG04\(T5L,TEMQ\)](#) [ACDBA1100LR-HF](#) [ACDBA1200-HF](#) [ACDBA240-HF](#) [ACDBA3100-HF](#) [CDBQC0530L-HF](#)
[ACDBA260LR-HF](#) [ACDBA1100-HF](#) [10BQ015-M3/5BT](#) [NRVBM120ET1G](#) [VSSB410S-M3/5BT](#) [1N5819T-G](#) [PDS1040Q-13](#) [B160BQ-13-F](#)
[SDM05U20CSP-7](#) [BAS 70-07 E6433](#) [B140S1F-7](#) [HSM560Je3/TR13](#) [DDB2265-000](#) [ZHCS506QTA](#) [HSM190Je3/TR13](#) [B330AF-13](#)
[ACDBUC0230-HF](#) [SDM1U100S1F-7](#) [MBR10200CTF-G1](#) [CDLL5712](#) [DMF2822-000](#)